## NSN 5961-01-059-0437

A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-059-0437 **Inclosure Material:** Glass and metal **Overall Length:** 0.375 inches **Overall Diameter:** 0.424 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-4 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.168 inches **Semiconductor Material:** Silicon **Power Rating Per Characteristic:** 10.0 watts forward power dissipation, dc **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: